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DMC2990UDJ-7

Diodes Incorporated

MOSFET MOSFET BVDSS

Any questions, please feel free to contact us. info@kaimte.com





Product Summary

Device	V _{(BR)DSS}	R _{DS(ON)} max	l _D max T _A = +25°C
		0.99Ω @ V _{GS} = 4.5V	450mA
Q1	20V	1.2Ω @ V _{GS} = 2.5V	400mA
QI	200	1.8Ω @ V _{GS} = 1.8V	330mA
		2.4Ω @ V _{GS} = 1.5V	300mA
	$\begin{array}{c} \mbox{Q2} \\ \mbox{Q2} \\ \mbox{-20V} \end{array} \begin{array}{c} \begin{tabular}{lllllllllllllllllllllllllllllllllll$	1.9Ω @ V _{GS} = -4.5V	-310mA
00		2.4Ω @ V _{GS} = -2.5V	-280mA
QZ		-240mA	
		5Ω @ V _{GS} = -1.5V	-180mA

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch





Top View

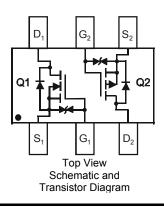
COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Very low Gate Threshold Voltage, 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 1mm
- Low Package Profile, 0.45mm Maximum Package height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3 & 4)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT963
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.027 grams (approximate)



Ordering Information (Note 5 & 6)

Part Number	Case	Packaging
DMC2990UDJ-7	SOT963	10K/Tape & Reel
DMC2990UDJ-7B	SOT963	10K/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

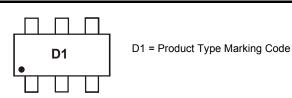
and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.</p>
4. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.

5. The options -7 and -7B stand for different taping orientations. Please refer to Diodes website at http://www.diodes.com for further details.

6. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information



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Maximum Ratings Q1 N-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage			V _{DSS}	20	V V mA mA
Gate-Source Voltage			V _{GSS}	±8	
	Steady State	T _A = +25°C T _A = +70°C	Ι _D	450 350	
Continuous Drain Current (Note 7) V_{GS} = 4.5V	t<5s	T _A = +25°C T _A = +70°C	Ι _D	520 410	
	Steady State	T _A = +25°C T _A = +70°C	Ι _D	330 260	mA
Continuous Drain Current (Note 7) V_{GS} = 1.8V	t<5s	T _A = +25°C T _A = +70°C	ID	390 310	mA
Maximum Continuous Body Diode Forward Curren		I _S	440	mA	
Pulsed Drain Current (Note 8)		I _{DM}	800	mA	

Maximum Ratings Q2 P-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
		T _A = +25°C T _A = +70°C	۱ _D	-310 -240	mA
Continuous Drain Current (Note 5) V _{GS} = -4.5V	t<5s	T _A = +25°C T _A = +70°C	۱ _D	-360 -280	mA
Continuous Drain Current (Nato 5) // = 1.9)/	Steady State	T _A = +25°C T _A = +70°C	lD	-240 -190	mA
Continuous Drain Current (Note 5) V _{GS} = -1.8V	t<5s	T _A = +25°C T _A = +70°C	ID	-280 -220	mA
Maximum Continuous Body Diode Forward Current	Is	-440	mA		
Pulsed Drain Current (Note 8)			I _{DM}	-800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 7)		PD	350	mW
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	Р	360	°C/W
	t<5s	$R_{\theta JA}$	270	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 7. Device mounted on FR-4 PCB, with minimum recommended pad layout.
8. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.



Electrical Characteristics Q1 N-CHANNEL (@T_A = +25°C, unless otherwise specified.)

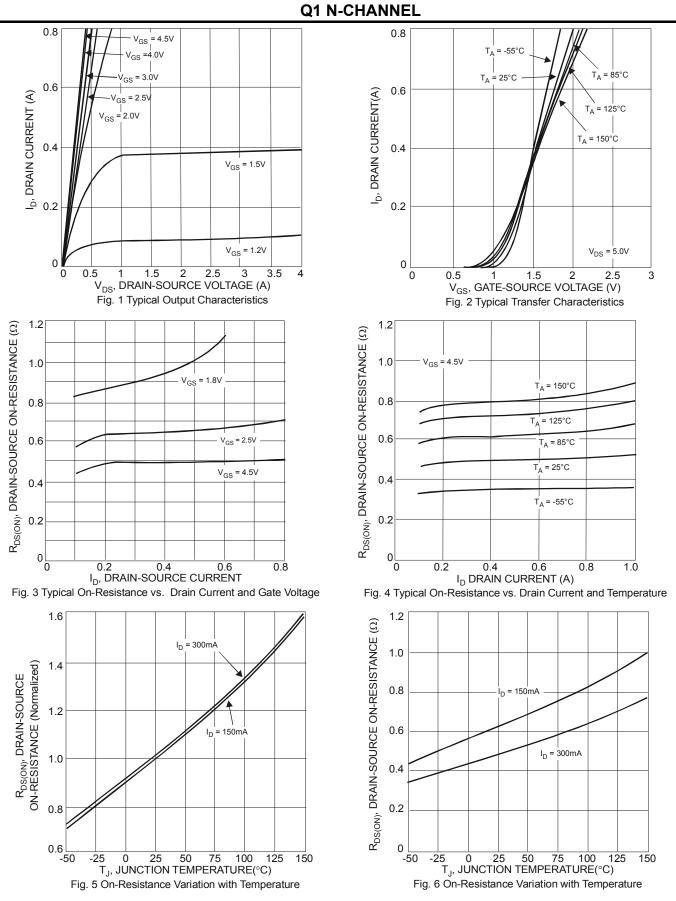
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	• • • • • • •				•		
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	V _{GS} = 0V, I _D = 250µA	
	IDSS	-	-	100	nA	V _{DS} = 16V, V _{GS} = 0V	
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$		-	-	50		$V_{DS} = 5V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	0.4	-	1.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		-	0.60	0.99		V _{GS} = 4.5V, I _D = 100mA	
		-	0.75	1.2		V _{GS} = 2.5V, I _D = 50mA	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	0.90	1.8	Ω	V _{GS} = 1.8V, I _D = 20mA	
		-	1.2	2.4		V _{GS} = 1.5V, I _D = 10mA	
		-	2.0	-		V _{GS} = 1.2V, I _D = 1mA	
Forward Transfer Admittance		180	850	-	mS	V _{DS} = 5V, I _D = 125mA	
Diode Forward Voltage	V _{SD}	-	0.6	1.0	V	V _{GS} = 0V, I _S = 10mA	
DYNAMIC CHARACTERISTICS (Note 10)			•	•		·	
Input Capacitance		-	27.6	-	pF		
Output Capacitance	Coss	-	4.0	-	pF	− V _{DS} = 15V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	2.8	-	pF	1 - 1.00012	
Gate Resistance	R _G	-	113	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	-	0.5	-	nC	V _{GS} = 4.5V, V _{DS} = 10V,	
Gate-Source Charge		-	0.07	-	nC	I _D = 250mA	
Gate-Drain Charge	Q _{gd}	-	0.07	-	nC	7	
Turn-On Delay Time	t _{D(on)}	-	4.0	-	ns		
Turn-On Rise Time	tr	-	3.3	-	ns	$V_{DD} = 15V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t _{D(off)}	-	19.0	-	ns	$R_{L} = 47\Omega, R_{G} = 2\Omega,$ $I_{D} = 200mA$	
Turn-Off Fall Time	t _f	-	6.4	-	ns		

Electrical Characteristics Q2 P-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	Gymbol	WIIII	ιyp	Μαλ	Onit	Test oblighter	
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	V _{GS} = 0V, I _D = -250µA	
		-	-	100	nA	$V_{DS} = -16V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$	IDSS	-	-	50		$V_{DS} = -5V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	-0.4	-	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
		-	1.2	1.9		V _{GS} = -4.5V, I _D = -100mA	
		-	1.5	2.4		V _{GS} = -2.5V, I _D = -50mA	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	2.1	3.4	Ω	V _{GS} = -1.8V, I _D = -20mA	
		-	2.5	5		V _{GS} = -1.5V, I _D = -10mA	
		-	4.0	-		V _{GS} = -1.2V, I _D = -1mA	
Forward Transfer Admittance	Y _{fs}	100	450	-	mS	V _{DS} = -5V, I _D = -125mA	
Diode Forward Voltage	V _{SD}	-	-0.6	-1.0	V	V _{GS} = 0V, I _S = -10mA	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	-	28.7	-	pF		
Output Capacitance	Coss	-	4.2	-	рF	− V _{DS} = -15V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	2.9	-	pF	1 - 1.00012	
Gate Resistance	R_{G}	-	399	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	-	0.4	-	nC		
Gate-Source Charge	Q _{gs}	-	0.08	-	nC	−V _{GS} = -4.5V, V _{DS} =- 10V, −I _D = -250mA	
Gate-Drain Charge	Q _{gd}	-	0.06	-	nC		
Turn-On Delay Time	t _{D(on)}	-	5.8	-	ns		
Turn-On Rise Time	tr	-	5.7	-	ns	V _{DD} = -15V, V _{GS} = -4.5V,	
Turn-Off Delay Time	t _{D(off)}	-	31.1	-	ns	$R_{G} = 2\Omega, I_{D} = -200 \text{mA}$	
Turn-Off Fall Time	t _f	-	16.4	-	ns	7	

Notes:9. Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to product testing.

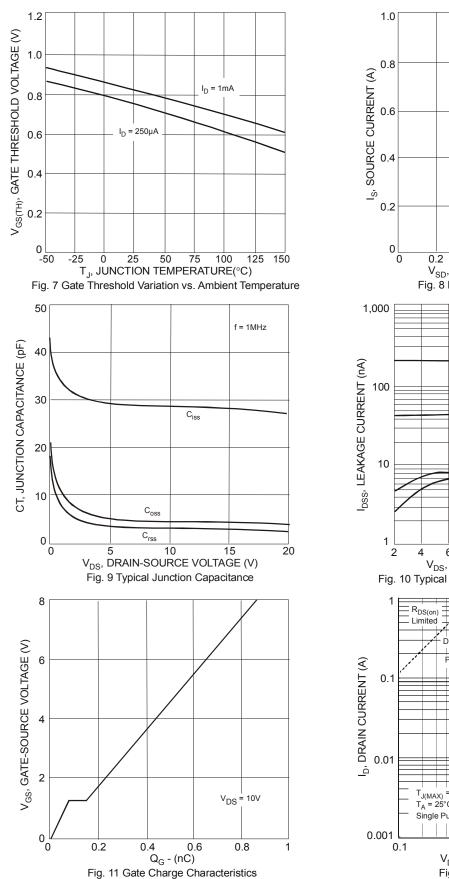


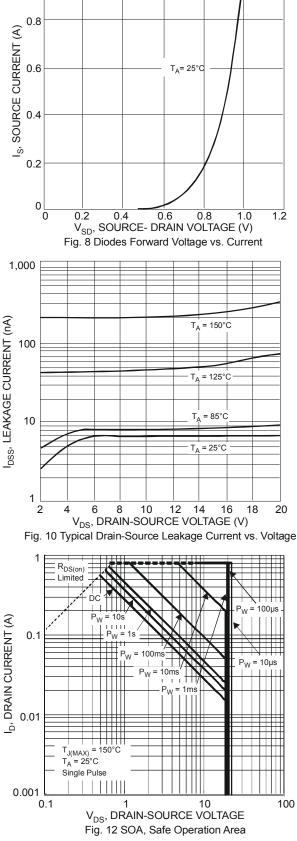


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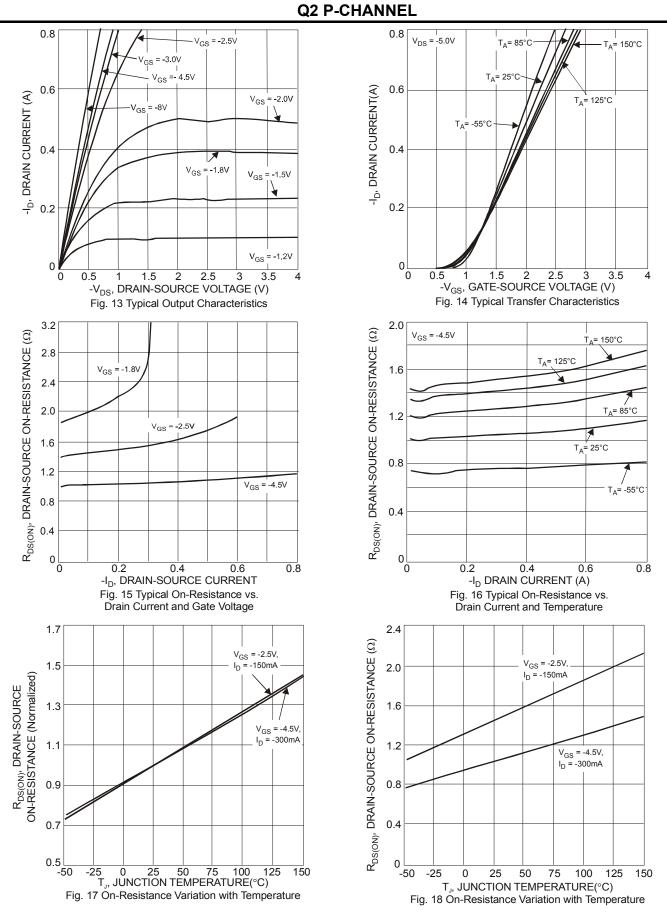






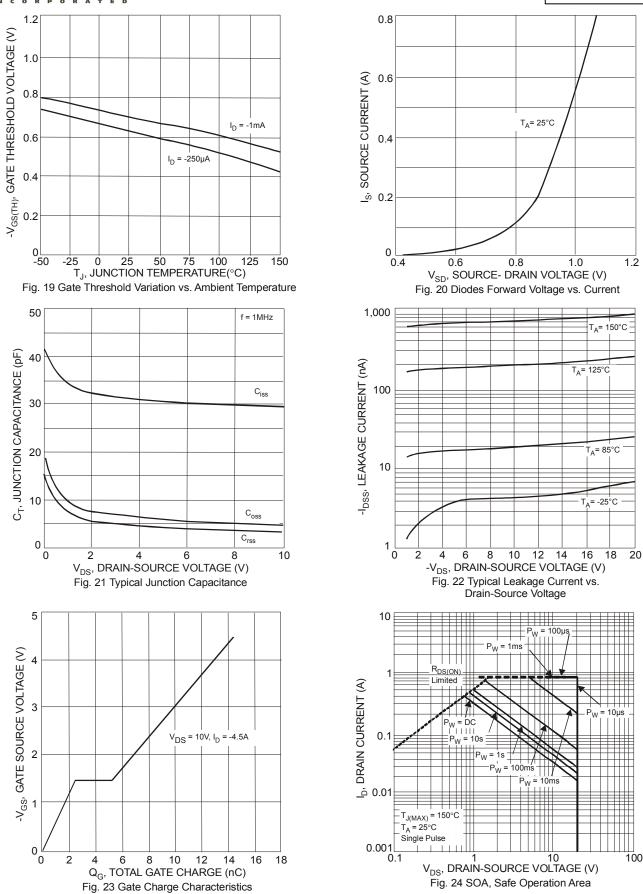
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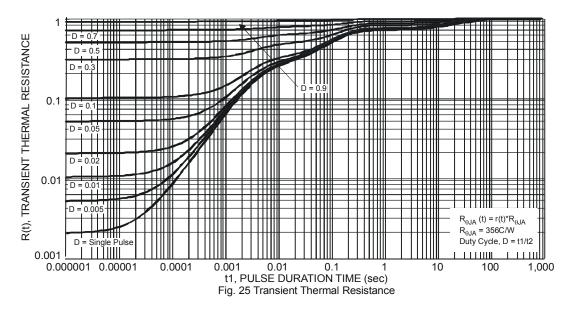
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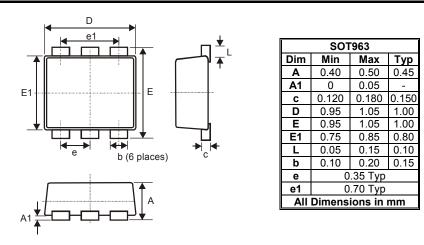


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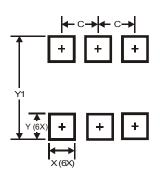




Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
С	0.350
Х	0.200
Y	0.200
Y1	1.100



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